CHENMKO ENTERPRISE CO.,LTD

CHDTB122JKPT

SURFACE MOUNT
PNP Digital Silicon Transistor
VOLTAGE 50 Volts CURRENT 500 mAmpere

Lead free devices

APPLICATION
* Switching circuit, Inverter, Interface circuit, Driver circuit.

FEATURE
* Small surface mounting type. (SC-59/SOT346)
* High current gain.
* Suitable for high packing density.
* Low colloector-emitter saturation.
* High saturation current capability.
* Internal isolated PNP transistors in one package.
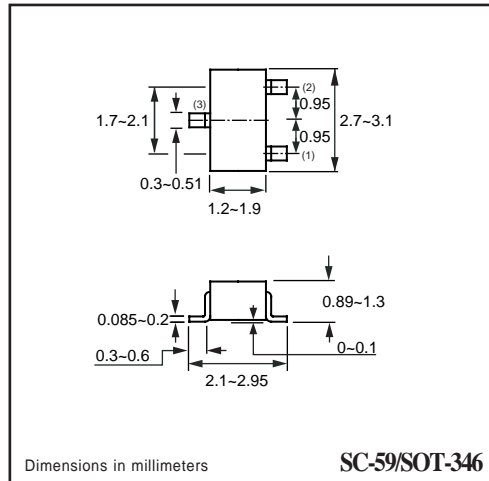* Built in bias resistor(R1=220 Ω, Typ.)

CONSTRUCTION
* One PNP transistors and bias of thin-film resistors in one package.

MARKING
JK2
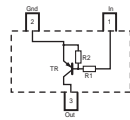
CIRCUIT

SC-59/SOT-346

Dimensions in millimeters SC-59/SOT-346

LIMITING VALUES
In accordance with the Absolute Maximum Rating System .

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_{CC}	Supply voltage		–	-50	V
V_{IN}	Input voltage		-5	+5	V
I_O	DC Output current		–	-500	mA
P_{TOT}	Total power dissipation	$T_{amb} \leq 25\ ^oC$, Note 1	–	200	mW
T_{STG}	Storage temperature		–55	+150	^oC
T_J	Junction temperature		–	150	^oC
$R_{\theta J-S}$	Thermal resistance	junction - soldering point	–	140	$^oC/W$

Note
1. Transistor mounted on an FR4 printed-circuit board.

RATING CHARACTERISTIC (CHDTB122JKPT)

CHARACTERISTICS

T_{amb} = 25 °C unless otherwise speciÞed.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$V_{I(off)}$	Input off voltage	I_O=-100uA; V_{CC}=-5.0V	-0.5	–	–	V
$V_{I(on)}$	Input on voltage	I_O=-30mA; V_O=-0.3V	–	–	-2.0	V
$V_{O(on)}$	Output voltage	I_O=-50mA; I_I=-0.25mA	–	- 0.1	- 0.3	V
I_I	Input current	V_I=-5V	–	–	-4.5	mA
$I_{C(off)}$	Output current	V_I=0V; V_{CC}=-30V	–	–	-10	uA
h_{FE}	DC current gain	I_O=-50mA; V_O=-5.0V	47	–	–	
R_1	Input resistor		154	220	286	Ω
R_2/R_1	Resistor ratio		17.1	21.3	25.6	
f_T	Transition frequency	I_E=50mA, V_{CE}=-10.0V f=100MHz	–	250	–	MHz

Note
1.Pulse test: tp≤300uS; δ≤0.02.